

FEATURES

- Low V_{OS} $25\mu V$ Max.
- Low V_{OS} Drift $0.6\mu V/\mu C$ Max.
- Very Stable $1.0\mu V/\text{Month}$ Max.
- Replaces 725, 108A/308A, AD510
- Wide Input Voltage Range $\pm 14V$

APPLICATIONS

- High-Stability Instrumentation Amplifiers
- Precision Absolute Value Circuits
- Adjustment-Free Precision Summing Amplifiers

DESCRIPTION

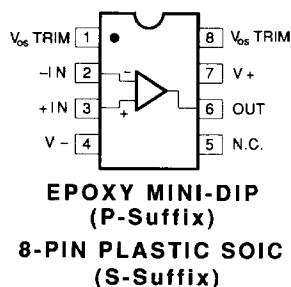
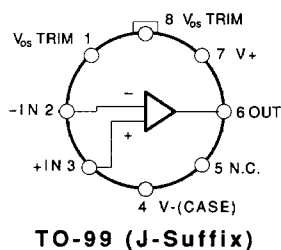
The OP-07 is a very low offset ($25\mu V$ max. for OP-07A), very low drift operational amplifier. Because of this low offset voltage, in many applications the OP-07 does not require external nulling. OP-07 also exhibits a very low input bias current ($\pm 2nA$ for OP-07A) and high gain (300,000). The OP-07 can be used as a direct replacement for 725 and 108A/308A (in TO-99 package) amplifiers, as well as for unnullled 741 amplifiers. Commercial temperature range devices, OP-07C, OP-07D and OP-07E are available in 8-pin plastic DIP packages, TO-99 metal cans and 8-pin plastic SOIC packages.

ORDERING INFORMATION†

$T_A = 25^\circ C$ $\Delta V_{OS} \text{ MAX}$ (μV)	PACKAGE			OPER. TEMP. RANGE
	TO-99 8-PIN	PLASTIC DIP 8-PIN	PLASTIC SOIC 8-PIN	
75	OP07EJ	OP07EP	OP07ES	COM
150	OP07CJ	OP07CP	OP07CS	COM
150	OP07DJ	OP07DP	OP07DS	COM

†All commercial and industrial temperature range parts are available with burn-in.

Pin Connections (Top View)



ABSOLUTE MAXIMUM RATINGS (Note 2)

Supply Voltage	$\pm 22V$
Internal Power Dissipation (Note 1)	500mW
Differential Input Voltage	$\pm 30V$
Input Voltage (Note 3)	$\pm 22V$
Output Short-Circuit Duration	Indefinite
Storage Temperature Range	
J	$-65^{\circ}C$ to $+150^{\circ}C$
P Package	$-65^{\circ}C$ to $+125^{\circ}C$
Operating Temperature Range	
OP-07E, OP-07C, OP-07D	$0^{\circ}C$ to $+70^{\circ}C$
Lead Temperature (Soldering, 60 sec.)	$300^{\circ}C$
DICE Junction Temperature (T_J)	$-65^{\circ}C$ to $+150^{\circ}C$

NOTES:

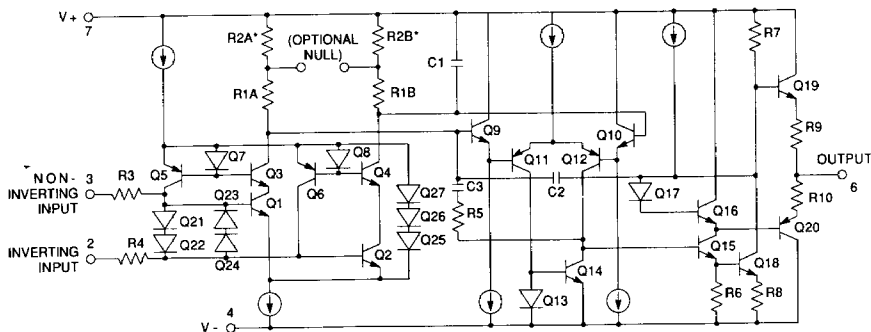
1. See table for maximum ambient temperature rating and derating factor.

PACKAGE TYPE	MAXIMUM AMBIENT TEMPERATURE FOR RATING	DERATE ABOVE MAXIMUM AMBIENT TEMPERATURE
TO-99 (J)	$80^{\circ}C$	$7.1mW/^{\circ}C$
8-Pin Plastic DIP (P)	$36^{\circ}C$	$5.6mW/^{\circ}C$

2. Absolute maximum ratings apply to both packaged parts and DICE, unless otherwise noted.

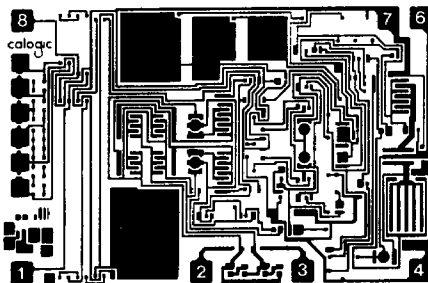
3. For supply voltages less than $\pm 22V$, the absolute maximum input voltage is equal to the supply voltage.

Simplified Schematic



*NOTE: R2A AND R2B ARE ELECTRONICALLY ADJUSTED ON CHIP AT FACTORY FOR MINIMUM INPUT OFFSET VOLTAGE.

Die Characteristics



DIE SIZE 0.099x0.066 inch, 6534 sq. mils
(2.515x1.676mm, 4.215 sq. mm)

1. TRIM
2. (-) INPUT
3. (+) INPUT
4. V-
6. OUTPUT
7. V+
8. TRIM

ELECTRICAL CHARACTERISTICS at $V_S = \pm 15V$, $T_A = 25^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-07A			OP-07			UNITS
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Input Offset Voltage	V_{OS}	(Note 1)	—	10	25	—	30	75	μV
Long-Term Input Offset Voltage Stability	$\Delta V_{OS}/\text{Time}$	(Note 2)	—	0.2	1.0	—	0.2	1.0	mV
Input Offset Current	I_{OS}		—	0.3	2.0	—	0.4	2.8	nA
Input Bias Current	I_B		—	± 0.7	± 2.0	—	± 1.0	± 3.0	nA
Input Noise Voltage	e_{n-p-p}	0.1Hz to 10Hz (Note 3)	—	0.35	0.6	—	0.35	0.6	μV_{p-p}
Input Noise Voltage Density	e_n	$f_O = 10\text{Hz}$ (Note 3)	—	10.3	18.0	—	10.3	18.0	$nV/\sqrt{Hz}$
		$f_O = 100\text{Hz}$ (Note 3)	—	10.0	13.0	—	10.0	13.0	
		$f_O = 1000\text{Hz}$ (Note 3)	—	9.6	11.0	—	9.6	11.0	
Input Noise Current	i_{n-p-p}	0.1Hz to 10Hz (Note 3)	—	14	30	—	14	30	pA_{p-p}
Input Noise Current Density	i_n	$f_O = 10\text{Hz}$ (Note 3)	—	0.32	0.80	—	0.32	0.80	$pA/\sqrt{Hz}$
		$f_O = 100\text{Hz}$ (Note 3)	—	0.14	0.23	—	0.14	0.23	
		$f_O = 1000\text{Hz}$ (Note 3)	—	0.12	0.17	—	0.12	0.17	
Input Resistance—Differential-Mode	R_{IN}	(Note 4)	30	80	—	20	60	—	M Ω
Input Resistance—Common-Mode	R_{INCM}		—	200	—	—	200	—	G Ω
Input Voltage Range	IVR		± 13	± 14	—	± 13	± 14	—	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 13V$	110	126	—	110	126	—	dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 3V$ to $\pm 18V$	—	4	10	—	4	10	$\mu V/V$
Large-Signal Voltage Gain	A_{VO}	$R_L \geq 2k\Omega$, $V_O = \pm 10V$	300	500	—	200	500	—	V/mV
		$R_L \geq 500\Omega$, $V_O = \pm 0.5V$, $V_S = \pm 3V$ (Note 4)	150	400	—	150	400	—	
Output Voltage Swing	V_O	$R_L \geq 10k\Omega$	± 12.5	± 13.0	—	± 12.5	± 13.0	—	V
		$R_L \geq 2k\Omega$	± 12.0	± 12.8	—	± 12.0	± 12.8	—	
		$R_L \geq 1k\Omega$	± 10.5	± 12.0	—	± 10.5	± 12.0	—	
Slew Rate	SR	$R_L \geq 2k\Omega$ (Note 3)	0.1	0.3	—	0.1	0.3	—	V/ μs
Closed-Loop Bandwidth	BW	$A_{VCL} = +1$ (Note 3)	0.4	0.6	—	0.4	0.6	—	MHz
Open-Loop Output Resistance	R_O	$V_O = 0$, $I_O = 0$	—	60	—	—	60	—	Ω
Power Consumption	P_d	$V_S = \pm 15V$, No Load	—	75	120	—	75	120	mW
		$V_S = \pm 3V$, No load	—	4	6	—	4	6	
Offset Adjustment Range		$R_p = 20k\Omega$	—	± 4	—	—	± 4	—	mV

NOTES:

1. OP-07A grade V_{OS} is measured approximately one minute after application of power. For all other grades V_{OS} is measured approximately 0.5 seconds after application of power.
2. Long-Term Input Offset Voltage Stability refers to the averaged trend line of V_{OS} vs. Time over extended periods after the first 30 days of operation.

Excluding the initial hour of operation, changes in V_{OS} during the first 30 operating days are typically $2.5\mu V$ —refer to typical performance curves.

3. Sample tested.
4. Guaranteed by design.

ELECTRICAL CHARACTERISTICS at $V_S = \pm 15V$, $T_A = 25^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-07E			OP-07C			OP-07D			UNITS
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Input Offset Voltage	V_{OS}	(Note 1)	—	30	75	—	60	150	—	60	150	μV
Long-Term V_{OS} Stability	$V_{OS}/Time$	(Note 2)	—	0.3	1.5	—	0.4	2.0	—	0.5	3.0	$\mu V/Mo$
Input Offset Current	I_{OS}		—	0.5	3.8	—	0.8	6.0	—	0.8	6.0	nA
Input Bias Current	I_B		—	± 1.2	± 4.0	—	± 1.8	± 7.0	—	± 2.0	± 12	nA
Input Noise Voltage	e_{np-p}	0.1Hz to 10Hz (Note 3)	—	0.35	0.6	—	0.38	0.65	—	0.38	0.65	μV_{p-p}
Input Noise Voltage Density	e_n	$f_O = 10Hz$	—	10.3	18.0	—	10.5	20.0	—	10.5	20.0	$nV/\sqrt{Hz}$
		$f_O = 100Hz$ (Note 3)	—	10.0	13.0	—	10.2	13.5	—	10.3	13.5	
		$f_O = 1000Hz$	—	9.6	11.0	—	9.8	11.5	—	9.8	11.5	
Input Noise Current	i_{np-p}	0.1Hz to 10Hz (Note 3)	—	14	30	—	15	35	—	15	35	pA_{p-p}
Input Noise Current Density	i_n	$f_O = 10Hz$	—	0.32	0.80	—	0.35	0.90	—	0.35	0.90	$pA/\sqrt{Hz}$
		$f_O = 100Hz$ (Note 3)	—	0.14	0.23	—	0.15	0.27	—	0.15	0.27	
		$f_O = 1000Hz$	—	0.12	0.17	—	0.13	0.18	—	0.13	0.18	
Input Resistance—Differential-Mode	R_{IN}	(Note 4)	15	50	—	8	33	—	7	31	—	$M\Omega$
Input Resistance—Common-Mode	R_{INCM}		—	160	—	—	120	—	—	120	—	$G\Omega$
Input Voltage Range	IVR		± 13	± 14	—	± 13	± 14	—	± 13	± 14	—	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 13V$	106	123	—	100	120	—	94	110	—	dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 3V$ to $\pm 18V$	—	5	20	—	7	32	—	7	32	$\mu V/V$
Large-Signal Voltage Gain	A_{VO}	$R_L \geq 2k\Omega$, $V_O = \pm 10V$	200	500	—	120	400	—	120	400	—	V/mV
		$R_L \geq 500\Omega$, $V_O = \pm 0.5V$	150	400	—	100	400	—	—	400	—	
		$V_S = \pm 3V$ (Note 3)	—	—	—	—	—	—	—	—	—	
Output Voltage Swing	V_O	$R_L \geq 10k\Omega$	± 12.5	± 13.0	—	± 12.0	± 13.0	—	± 12.0	± 13.0	—	V
		$R_L \geq 2k\Omega$	± 12.0	± 12.8	—	± 11.5	± 12.8	—	± 11.5	± 12.8	—	
		$R_L \geq 1k\Omega$	± 10.5	± 12.0	—	—	± 12.0	—	—	± 12.0	—	
Slew Rate	SR	$R_L \geq 2k\Omega$ (Note 3)	0.1	0.3	—	0.1	0.3	—	0.1	0.3	—	$V/\mu s$
Closed-Loop Bandwidth	BW	$A_{VCL} = +1.0$ (Note 5)	0.4	0.6	—	0.4	0.6	—	0.4	0.6	—	MHz
Open-Loop Output Resistance	R_O	$V_O = 0$, $I_O = 0$	—	60	—	—	60	—	—	60	—	Ω
Power Consumption	P_d	$V_S = \pm 15V$, No Load	—	75	120	—	80	150	—	80	150	mW
		$V_S = \pm 3V$, No load	—	4	6	—	4	8	—	4	8	
Offset Adjustment Range		$R_p = 20k\Omega$	—	± 4	—	—	± 4	—	—	± 4	—	mV

NOTES:

1. Input Offset Voltage measurements are performed by automated test equipment approximately 0.5 seconds after application of power.
2. Long-Term Input Offset Voltage Stability refers to the averaged trend line of V_{OS} vs. Time over extended periods after the first 30 days of operation.

- Excluding the initial hour of operation, changes in V_{OS} during the first 30 operating days are typically $2.5\mu V$ —refer to typical performance curves.
3. Sample tested.
 4. Guaranteed by design.

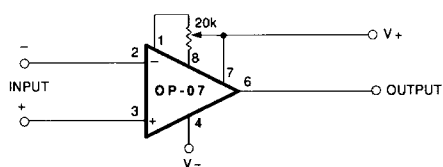
ELECTRICAL CHARACTERISTICS at $V_S = \pm 15V$, $0^\circ C \leq T_A \leq +70^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-07E			OP-07C			OP-07D			UNITS
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Input Offset Voltage	V_{OS}	(Note 1)	—	45	130	—	85	250	—	85	250	μV
Average Input Offset Voltage Drift Without External Trim	TCV_{OS}	(Note 3)	—	0.3	1.3	—	0.5	1.8	—	0.7	2.5	$\mu V/^\circ C$
With External Trim	TCV_{OSn}	$R_p = 20k\Omega$ (Note 3)	—	0.3	1.3	—	0.4	1.6	—	0.7	2.5	$\mu V/^\circ C$
Input Offset Current	I_{OS}		—	0.9	5.3	—	1.6	8.0	—	1.6	8.0	nA
Average Input Offset Current Drift	TCI_{OS}	(Note 2)	—	8	35	—	12	50	—	12	50	$pA/^\circ C$
Input Bias Current	I_B		—	± 1.5	± 5.5	—	± 2.2	± 9.0	—	± 3.0	± 14	nA
Average Input Bias Current Drift	TCI_B	(Note 2)	—	13	35	—	18	50	—	18	50	$pA/^\circ C$
Input Voltage Range	IVR		± 13.0	± 13.5	—	± 13.0	± 13.5	—	± 13.0	± 13.5	—	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 13V$	103	123	—	97	120	—	94	106	—	dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 3V$ to $\pm 18V$	—	7	32	—	10	51	—	10	51	$\mu V/V$
Large-Signal Voltage Gain	A_{VO}	$R_L \geq 2k\Omega$, $V_O = \pm 10V$	180	450	—	100	400	—	100	400	—	V/mV
Output Voltage Swing	V_O	$R_L \geq 2k\Omega$	± 12	± 12.6	—	± 11	± 12.6	—	± 11	± 12.6	—	V

NOTES:

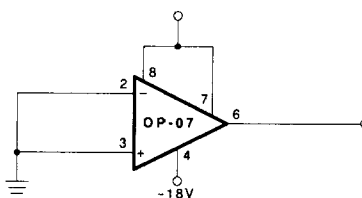
1. Input offset voltage measurements are performed by automated test equipment approximately 0.5 seconds after application of power.
2. Sample tested.
3. Guaranteed by design.

Optional Offset Nulling Circuit



PINOUTS SHOWN FOR J, P, AND Z PACKAGES

Burn-In Circuit



PINOUTS SHOWN FOR J, P, AND Z PACKAGES